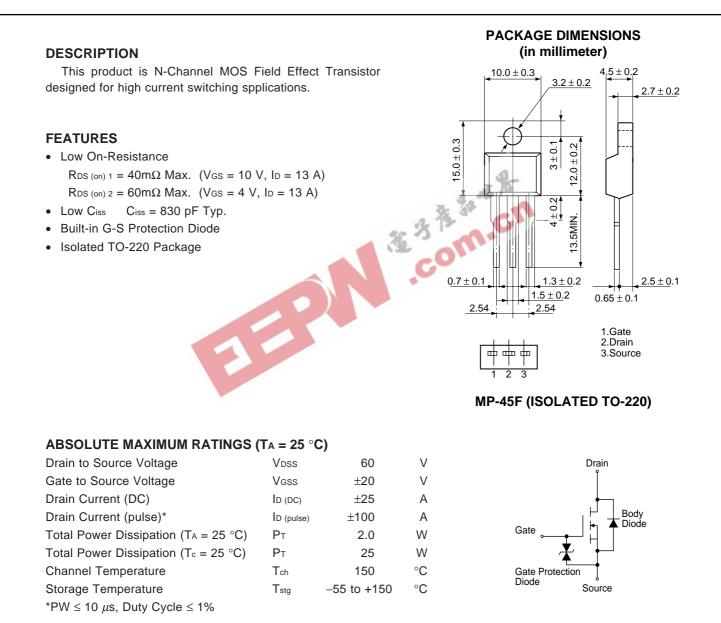


MOS Field Effect Power Transistors 2SK2723

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE



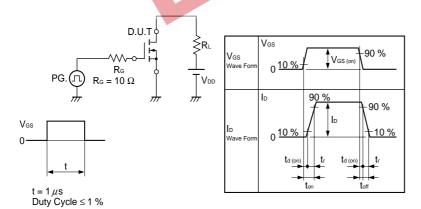
The diode connected between the gate and source of the transistor serves as a protector against ESD. When this deveice acutally used, an additional protection circuit is externally required if voltage exceeding the rated voltage may be applied to this device.

The information in this document is subject to change without notice.

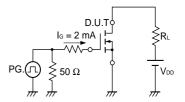
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

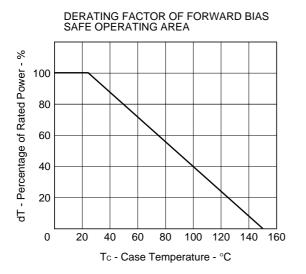
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source	RDS (on) 1	Vgs = 10 V, Id = 13 A		28	40	mΩ
On-state Resistance	RDS (on) 2	Vgs = 4 V, Id = 13 A		45	60	mΩ
Gate to Source Cutoff Voltage	VGS (off)	Vds = 10 V, Id = 1 mA	1.0	1.6	2.0	V
Forward Transfer Admittance	y _{fs}	Vds = 10 V, Id = 13 A	8.0	18		S
Drain Leakage Current	Ibss	$V_{DS} = 60 V, V_{GS} = 0$			10	μΑ
Gate to Source Leakage Current	Igss	$V_{GS} = \pm 20 V$, $V_{DS} = 0$			±10	μA
Input Capacitance	Ciss	Vds = 10 V		830		pF
Output Capacitance	Coss	V _{GS} = 0		430		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		185		pF
Turn-On Delay Time	td (on)	ID = 13 A		21		ns
Rise Time	tr	$V_{GS (on)} = 10 V$		185		ns
Turn-Off Delay Time	td (off)	Vdd = 30 V		100		ns
Fall Time	tr	R _G = 10 Ω		110		ns
Total Gate Charge	QG	ID = 25 A		35		nC
Gate to Source Charge	QGS	VDD = 48 V		2.8		nC
Gate to Drain Charge	Qgd	Vgs = 10 V 🔥 🖗 🚺		15		nC
Body Diode Forward Voltage	VF (S-D)	$I_{D} = 25 \text{ A}$ $V_{DD} = 48 \text{ V}$ $V_{GS} = 10 \text{ V}$ $I_{F} = 25 \text{ A}, \text{ V}_{GS} = 0$ $I_{T} = 25 \text{ A}, \text{ V}_{GS} = 0$		1.0		V
Reverse Recovery Time	trr	IF = 25 A, VGs = 0		60		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		125		nC

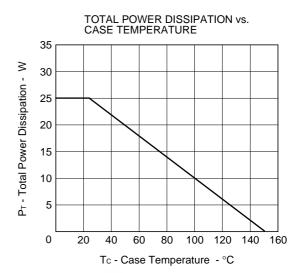
Test Circuit 1 Switching Time



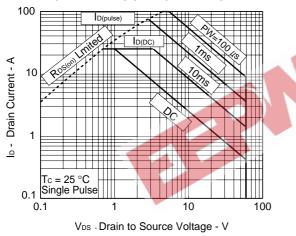
Test Circuit 2 Gate Charge



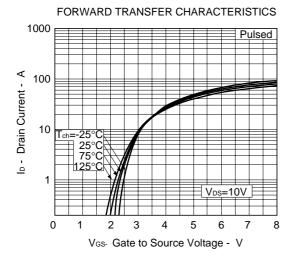




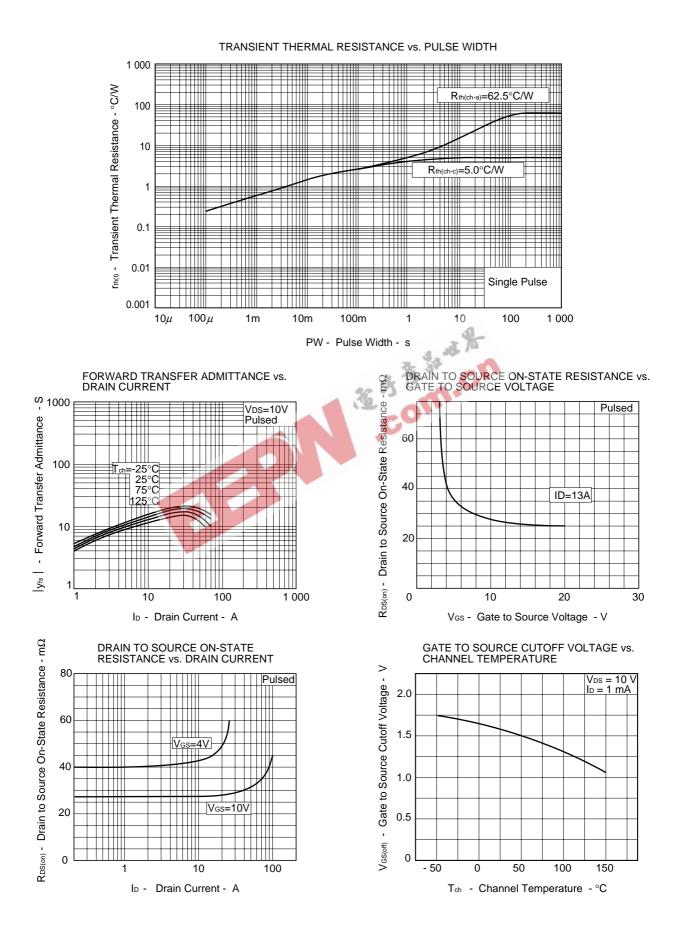
FORWARD BIAS SAFE OPERATING AREA

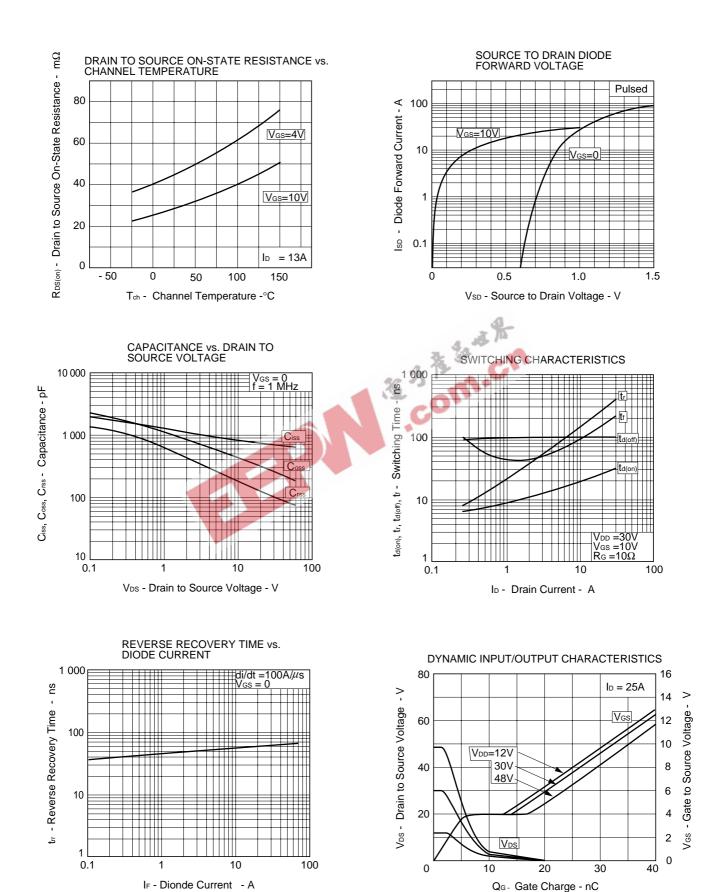


DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



3





REFERENCE

Document Name	Document No.	
NEC semiconductor device reliability/quality control system.	TEI-1202	
Quality grade on NEC semiconductor devices.	IEI-1209	
Semiconductor device mounting technology manual.	C10535E	
Semiconductor device package manual.	C10943X	
Guide to quality assurance for semiconductor devices.	MEI-1202	
Semiconductor selection guide.	X10679E	
Power MOS FET features and application switching power supply.	TEA-1034	
Application circuits using Power MOS FET.	TEA-1035	
Safe operating area of Power MOS FET.	TEA-1037	



[MEMO]



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- Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
- Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.

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